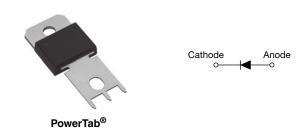


FRED Pt® Ultrafast Soft Recovery Diode, 150 A



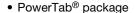
LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I _{F(AV)}	150 A			
V _R	600 V			
V _F at I _F	1.08 V			
I _{FSM}	1200 A			
t _{rr} (typ.)	50 ns			
T _J max.	175 °C			
Snap factor	0.5			
Package	PowerTab [®]			
Circuit configuration	Single			

FEATURES

- Ultrafast recovery time
- 175 °C max. operating junction temperature
- Screw mounting only
- Designed and qualified according to JEDEC®-JESD 47





Pb-free



BENEFITS

- Reduced RFI and EMI
- Higher frequency operation
- · Reduced snubbing
- · Reduced parts count

DESCRIPTION/APPLICATIONS

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems.

The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

MECHANICAL DATA

Case: PowerTab®

Molding compound meets UL 94 V-0 flammability rating

Terminal: nickel plated, screwable

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	V _R		600	V	
Continuous forward current	I _{F(AV)}	T _C = 89 °C	150	Α	
Single pulse forward current	I _{FSM}	T _C = 25 °C	1200	A	
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS MIN. TYP.		MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 200 μΑ	600	-	-	
		I _F = 150 A	-	1.27	1.63	V
Forward voltage	V_{F}	I _F = 150 A, T _J = 125 °C	-	1.15	1.43	
		I _F = 150 A, T _J = 175 °C	ı	1.08	1.32	
Reverse leakage current I _R		$V_R = V_R$ rated	-	-	8	μA
		T _J = 150 °C, V _R = V _R rated	-	-	0.5	mA
Junction capacitance	C _T	V _R = 600 V - 70 -		pF		
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	3.5	-	nH



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CON	TEST CONDITIONS		TYP.	MAX.	UNITS
Reverse recovery time t _{rr}	$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	50	ı		
	+	$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A}$	t = 200 A/µs, V _R = 30 V		40	ı	
	۲rr	T _J = 25 °C		-	100	-	ns
	T _J = 125 °C		-	210	-]	
Peak recovery current I _{RRM}	ı	T _J = 25 °C	I _F = 50 A V _R = 200 V	-	10.5	-	А
	T _J = 125 °C	v _R = 200 v dI _F /dt = 200 A/μs	-	22	-		
Reverse recovery charge Q _{rr}	0	T _J = 25 °C		-	550	-	nC
	Q _{rr}	T _J = 125 °C		-	2350		

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction to case	R _{thJC}		-	-	0.35	K/W
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.2	-	IV/VV
Weight			-	-	5.02	g
Mounting torque			1.2 (10)	-	2.4 (20)	kgf · cm (lbf · in)
Marking device		Case style PowerTab®		EBU ⁻	15006	

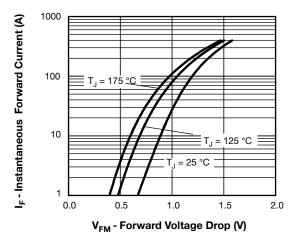


Fig. 1 - Maximum Forward Voltage Drop Characteristics

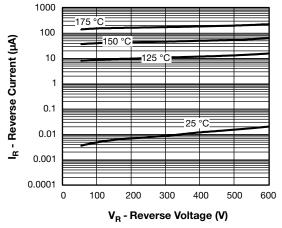


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



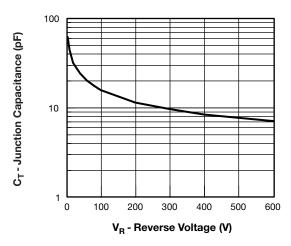


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

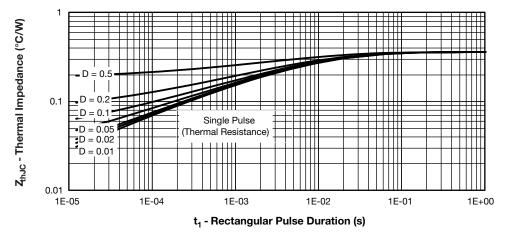


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

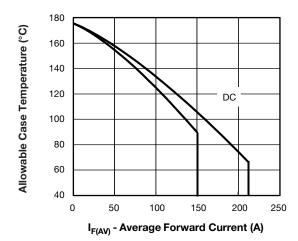


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

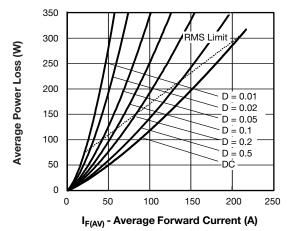


Fig. 6 - Forward Power Loss Characteristics

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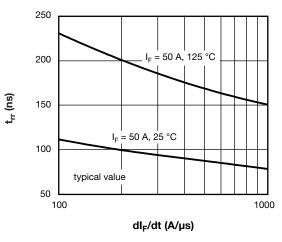


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

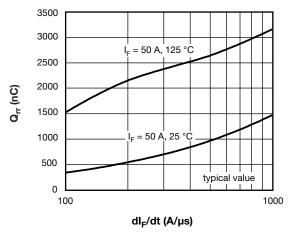
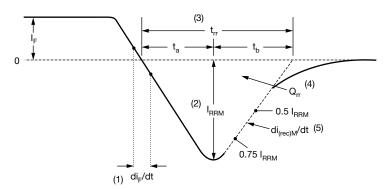


Fig. 8 - Typical Stored Charge vs. dl_E/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) ${\rm Q_{rr}}$ area under curve defined by ${\rm t_{rr}}$ and ${\rm I_{RRM}}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

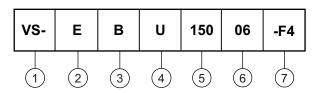
(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Single diode

3 - PowerTab®

Ultrafast recovery

5 - Current rating (150 = 150 A)

Voltage rating (06 = 600 V)

7 - Environmental digit:

-F4 = RoHS-compliant and totally lead (Pb)-free

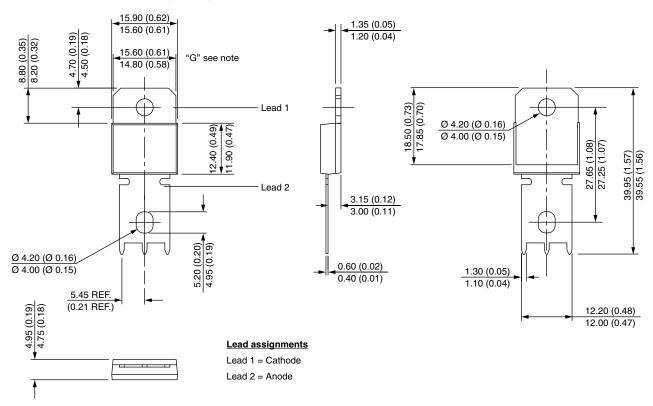
ORDERING INFORMATION (Example)						
PREFERRED P/N	EFERRED P/N QUANTITY PER T/R BASE QUANTITY PACKAGING DESCRIPTION					
VS-EBU15006-F4	25	375	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95240			
Part marking information	www.vishay.com/doc?95467			
Application note	www.vishay.com/doc?95179			
SPICE model	www.vishay.com/doc?97099			



PowerTab®

DIMENSIONS in millimeters (inches)



Note:

Outline conform to JEDEC® TO-275, except for dimension "G" only



Legal Disclaimer Notice

Vishay

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